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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE
INFORMATION DISCLOSURE STATEMENT

APPLICANT(S): Masahito Uchikoshi et al.) ATTORNEYS DOCKET NO:
SERIAL NO: 09/966,861) 09799107-0009
Filed: September 28, 2001) Group Art Unit: 1742
Title: HIGH PURITY COBALT, METHOD OF) Examiner: Unknown
MANUFACTURING THEREOF, AND HIGH)
PURITY COBALT TARGETS)

Hon. Assistant Commissioner for Patents
Washington, DC 20231

Sir:

In accordance with the provisions of 37 C.F.R. § 1.56, Applicants request that citation and examination of the references identified on the attached PTO-1449 form, copies of which are enclosed herewith in accordance with 37 C.F.R. § 1.98, be made during the course of examination of the above-referenced application for United States Letters Patent.

I. SUBMITTED UNITED STATES PATENT REFERENCES

<u>Reference</u>	<u>Number</u>	<u>Patentee</u>	<u>Issue Date</u>
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II. SUBMITTED FOREIGN PATENT REFERENCES

<u>Reference</u>	<u>Number</u>	<u>Country</u>	<u>Date of Publication</u>
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III. OTHER PRIOR ART-NON PATENT LITERATURE DOCUMENTS

AL V.G. Glebovsky et al., "Electron-Beam Floating Zone Growing Of High-Purity Cobalt Crystals," Materials Letters, Institute of Solid State Physics, 142432 Chernogolovka, Russian Federation, 12/12/97, pp. 308-314.

IV. EXPLANATION OF RELEVANCE

Reference AL was cited by the inventors in the specification that was filed on September 28, 2001. A copy of the publication is submitted herewith.

RECEIVED
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Submitted by,

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